

31046 U.S. PTO
10/026950



PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPLICATION	FILING DATE	CLASS	SUBCLASS	GROUP ART UNIT	EXAMINER
APPL NUM 10026950	FILING DATE 12/27/2001	CLASS 257	SUBCLASS 197	GAU 2841	EXAMINER SRS BAUMFISTER

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Brook

**CONTINUING DATA VERIFIED:

** FOREIGN APPLICATIONS VERIFIED:
JAPAN P2000-398417 12/27/2000

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PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO 33035M084
Foreign priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no		35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no	
Verified and Acknowledged Examiners's initials		TITLE : Heterojunction bipolar transistor and method of making heterojunction bipolar transistor	

U.S. DEPT. OF COMM./PAT. & TM-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
Assistant Examiner		Total Claims	Print Claim for O.G.
Primary Examiner		DRAWING	
PREPARED FOR ISSUE		Sheets Drawg.	Figs. Drawg.
Application Examiner		Print Fig.	
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